

Small Signal Diode

1N91x, 1N4x48, FDLL914, FDLL4x48

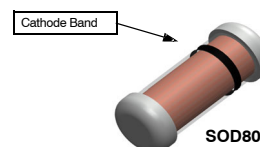
ORDERING INFORMATION

Part Number	Marking	Package	Packing Method
1N914	914	DO-204AH (DO-35)	Bulk
1N914-T50A	914	DO-204AH (DO-35)	Ammo
1N914TR	914	DO-204AH (DO-35)	Tape and Reel
1N914ATR	914A	DO-204AH (DO-35)	Tape and Reel
1N914B	914B	DO-204AH (DO-35)	Bulk
1N914BTR	914B	DO-204AH (DO-35)	Tape and Reel
1N916	916	DO-204AH (DO-35)	Bulk
1N916A	916A	DO-204AH (DO-35)	Bulk
1N916B	916B	DO-204AH (DO-35)	Bulk
1N4148	4148	DO-204AH (DO-35)	Bulk
1N4148TA	4148	DO-204AH (DO-35)	Ammo
1N4148-T26A	4148	DO-204AH (DO-35)	Ammo
1N4148-T50A	4148	DO-204AH (DO-35)	Ammo
1N4148TR	4148	DO-204AH (DO-35)	Tape and Reel
1N4148-T50R	4148	DO-204AH (DO-35)	Tape and Reel
1N4448	4448	DO-204AH (DO-35)	Bulk
1N4448TR	4448	DO-204AH (DO-35)	Tape and Reel
FDLL914	Black	SOD-80	Tape and Reel
FDLL914A	Black	SOD-80	Tape and Reel
FDLL914B	Black	SOD-80	Tape and Reel
FDLL4148	Black	SOD-80	Tape and Reel
FDLL4148-D87Z	Black	SOD-80	Tape and Reel
FDLL4448	Black	SOD-80	Tape and Reel
FDLL4448-D87Z	Black	SOD-80	Tape and Reel



DO-35

Cathode is denoted with a black band



SOD80

LL-34

THE PLACEMENT OF THE EXPANSION GAP HAS NO RELATIONSHIP TO THE LOCATION OF THE CATHODE TERMINAL

SOD-80 COLOR BAND MARKING

DEVICE 1ST BAND

FDLL914	BLACK
FDLL914A	BLACK
FDLL914B	BLACK
FDLL4148	BLACK
FDLL4448	BLACK

-1st band denotes cathode terminal and has wider width

1N91x, 1N4x48, FDLL914, FDLL4x48

ABSOLUTE MAXIMUM RATINGS (Values are at $T_A = 25^\circ\text{C}$ unless otherwise noted) (Note 1)

Rating	Symbol	Value	Unit
Maximum Repetitive Reverse Voltage	V_{RRM}	100	V
Average Rectified Forward Current	I_O	200	mA
DC Forward Current	I_F	300	mA
Recurrent Peak Forward Current	I_f	400	mA
Non-repetitive Peak Forward Surge Current	I_{FSM}	1.0	A
		4.0	A
Storage Temperature Range	T_{STG}	-65 to +200	$^\circ\text{C}$
Operating Junction Temperature Range	T_J	-55 to +175	$^\circ\text{C}$

Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.

1. These ratings are limiting values above which the serviceability of the diode may be impaired.

THERMAL CHARACTERISTICS

Parameter	Symbol	Max	Unit
Power Dissipation	P_D	500	mW
Thermal Resistance, Junction-to-Ambient	$R_{\theta JA}$	300	$^\circ\text{C}$

ELECTRICAL CHARACTERISTICS (Values are at $T_A = 25^\circ\text{C}$ unless otherwise noted) (Note 2)

Symbol	Parameter		Conditions	Min	Max	Unit
V_R	Breakdown Voltage		$I_R = 100 \mu\text{A}$	100		V
			$I_R = 5.0 \mu\text{A}$	75		V
V_F	Forward Voltage	914B / 4448	$I_F = 5.0 \text{ mA}$	0.62	0.72	V
		916B	$I_F = 5.0 \text{ mA}$	0.63	0.73	V
		914 / 916 / 4148	$I_F = 10 \text{ mA}$		1.0	V
		914A / 916A	$I_F = 20 \text{ mA}$		1.0	V
		916B	$I_F = 20 \text{ mA}$		1.0	V
		914B / 4448	$I_F = 100 \text{ mA}$		1.0	V
I_R	Reverse Leakage		$V_R = 20 \text{ V}$		0.025	μA
			$V_R = 20 \text{ V}, T_A = 150^\circ\text{C}$		50	μA
			$V_R = 75 \text{ V}$		5.0	μA
C_T	Total Capacitance	916/916A/916B/4448	$V_R = 0, f = 1.0 \text{ MHz}$		2.0	pF
		914/914A/914B/4148	$V_R = 0, f = 1.0 \text{ MHz}$		4.0	pF
t_{rr}	Reverse Recovery Time		$I_F = 10 \text{ mA}, V_R = 6.0 \text{ V (600 mA)}$ $I_{rr} = 1.0 \text{ mA}, R_L = 100 \Omega$		4.0	ns

Product parametric performance is indicated in the Electrical Characteristics for the listed test conditions, unless otherwise noted. Product performance may not be indicated by the Electrical Characteristics if operated under different conditions.

2. Non-recurrent square wave $P_W = 8.3 \text{ ms}$.

TYPICAL PERFORMANCE CHARACTERISTICS

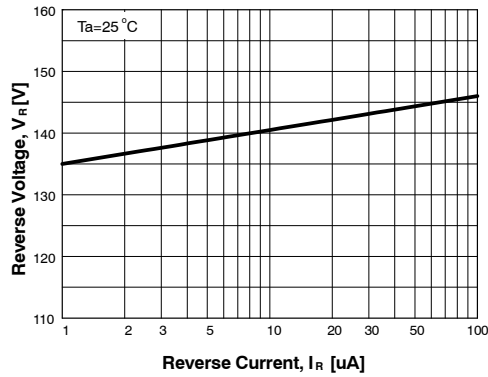


Figure 1. Reverse Voltage vs. Reverse Current
 $B_V - 1.0$ to $100 \mu A$

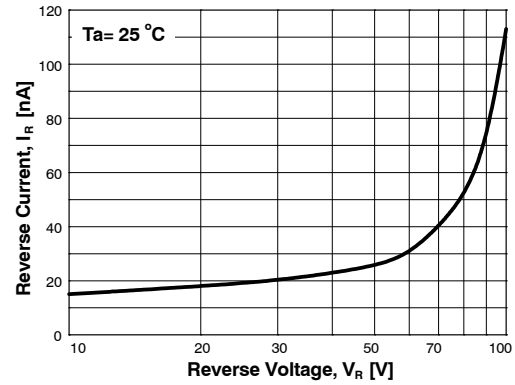


Figure 2. Reverse Current vs. Reverse Voltage
 $I_R - 10$ to $100 V$

GENERAL RULE: The Reverse Current of a diode will approximately double for every ten (10) Degree C increase in Temperature

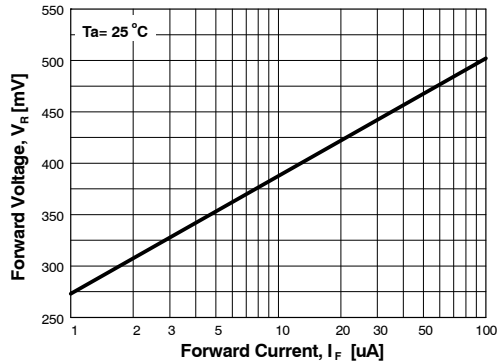


Figure 3. Forward Voltage vs. Forward Current
 $V_F - 1$ to $100 \mu A$

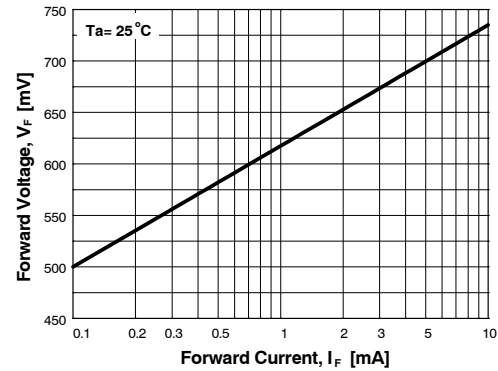


Figure 4. Forward Voltage vs. Forward Current
 $V_F - 0.1$ to $10 mA$

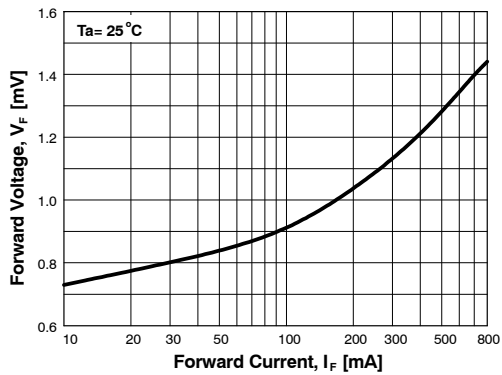


Figure 5. Forward Voltage vs. Forward Current
 $V_F - 10$ to $800 mA$

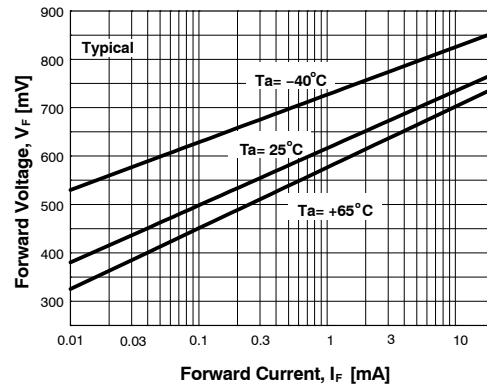


Figure 6. Forward Voltage vs. Ambient Temperature
 $V_F - 0.01 - 20 mA (-40$ to $+65^\circ C)$

1N91x, 1N4x48, FDLL914, FDLL4x48

TYPICAL PERFORMANCE CHARACTERISTICS

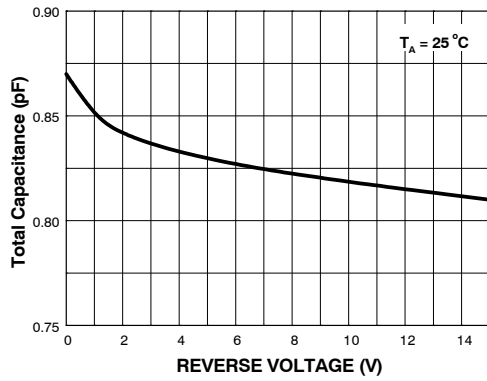


Figure 7. Total Capacitance

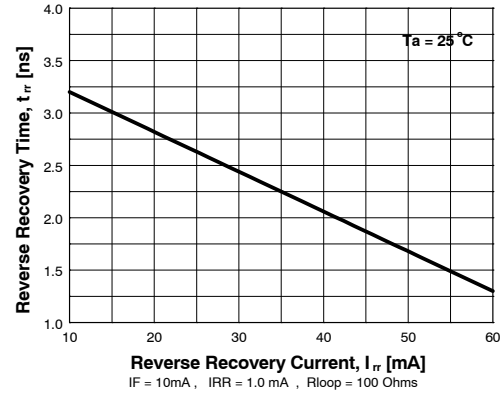


Figure 8. Reverse Recovery Time vs. Reverse Recovery Current

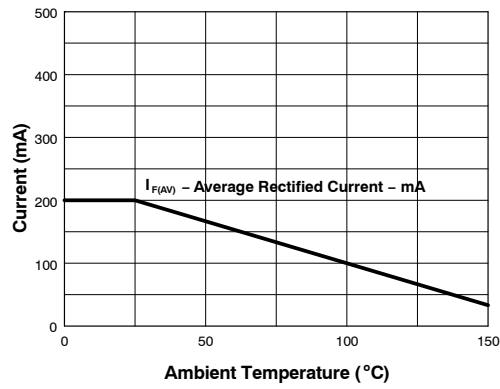


Figure 9. Average Rectified Current ($I_{F(AV)}$) vs. Ambient Temperature (T_A)

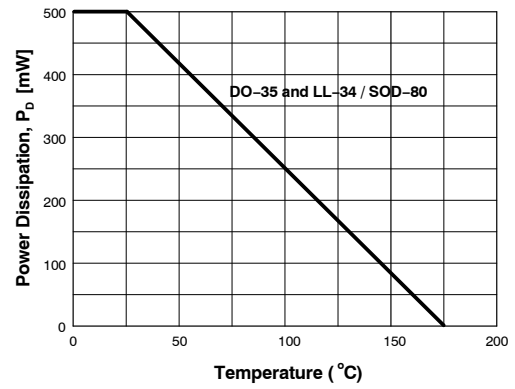
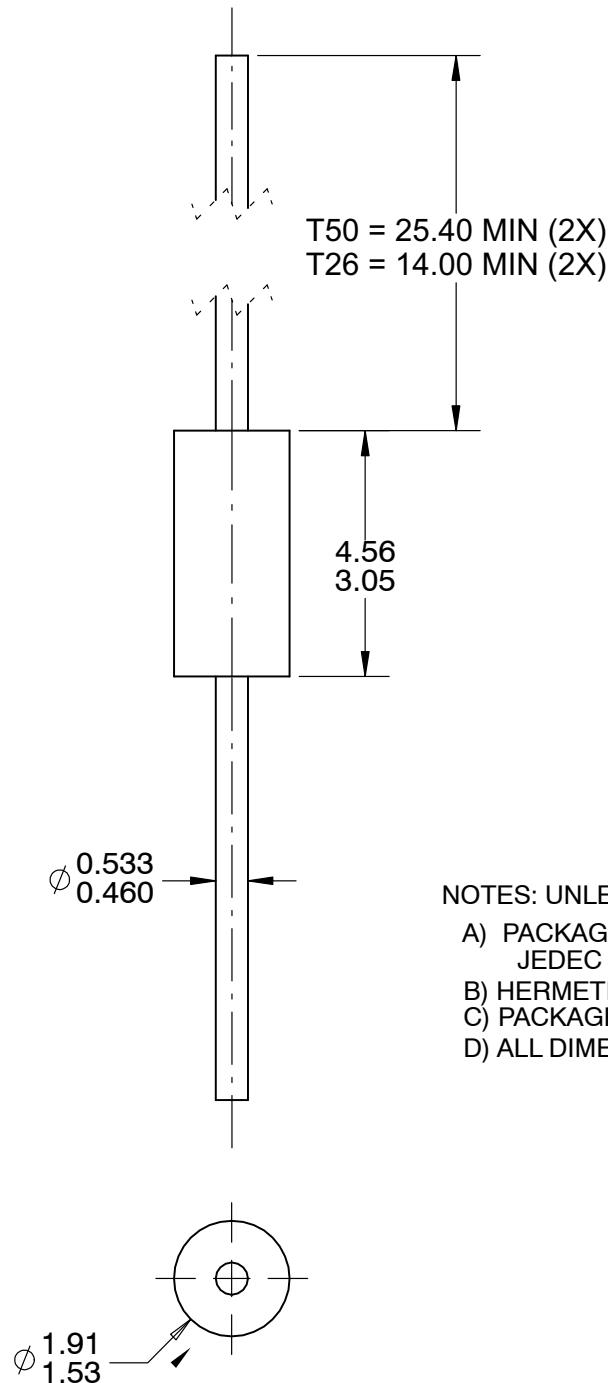


Figure 10. Power Derating Curve

AXIAL LEAD
CASE 017AG
ISSUE O


DATE 31 AUG 2016



NOTES: UNLESS OTHERWISE SPECIFIED

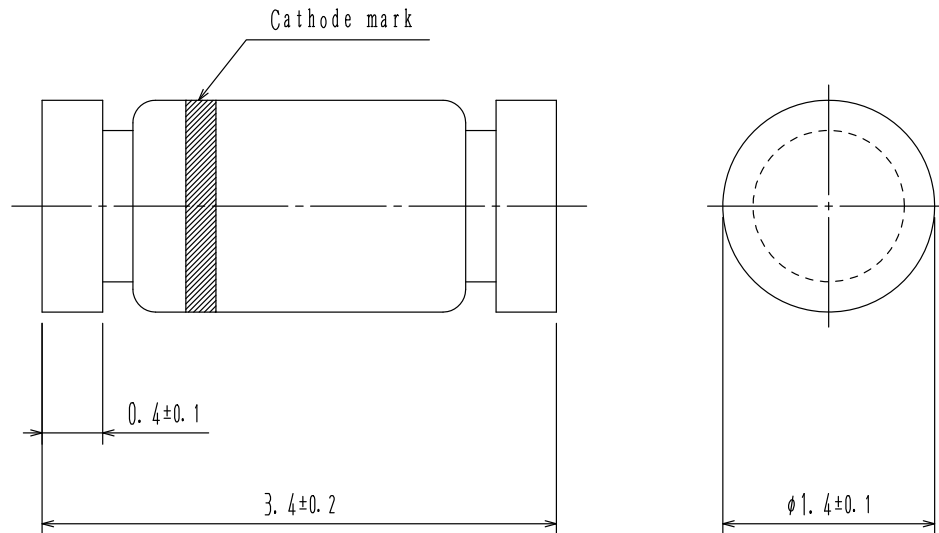
- A) PACKAGE STANDARD REFERENCE:
JEDEC DO-204, VARIATION AH.
- B) HERMETICALLY SEALED GLASS PACKAGE.
- C) PACKAGE WEIGHT IS 0.137 GRAM.
- D) ALL DIMENSIONS ARE IN MILLIMETERS.

DOCUMENT NUMBER:	98AON13443G	Electronic versions are uncontrolled except when accessed directly from the Document Repository. Printed versions are uncontrolled except when stamped "CONTROLLED COPY" in red.
DESCRIPTION:	AXIAL LEAD	PAGE 1 OF 1


ON Semiconductor and  are trademarks of Semiconductor Components Industries, LLC dba ON Semiconductor or its subsidiaries in the United States and/or other countries. ON Semiconductor reserves the right to make changes without further notice to any products herein. ON Semiconductor makes no warranty, representation or guarantee regarding the suitability of its products for any particular purpose, nor does ON Semiconductor assume any liability arising out of the application or use of any product or circuit, and specifically disclaims any and all liability, including without limitation special, consequential or incidental damages. ON Semiconductor does not convey any license under its patent rights nor the rights of others.

MiniMELF / SOD-80
CASE 100AD
ISSUE O

DATE 30 APR 2012



DOCUMENT NUMBER:	98AON79582E	Electronic versions are uncontrolled except when accessed directly from the Document Repository. Printed versions are uncontrolled except when stamped "CONTROLLED COPY" in red.
DESCRIPTION:	MINIMELF / SOD-80	PAGE 1 OF 1

ON Semiconductor and  are trademarks of Semiconductor Components Industries, LLC dba ON Semiconductor or its subsidiaries in the United States and/or other countries. ON Semiconductor reserves the right to make changes without further notice to any products herein. ON Semiconductor makes no warranty, representation or guarantee regarding the suitability of its products for any particular purpose, nor does ON Semiconductor assume any liability arising out of the application or use of any product or circuit, and specifically disclaims any and all liability, including without limitation special, consequential or incidental damages. ON Semiconductor does not convey any license under its patent rights nor the rights of others.

onsemi, **Onsemi**, and other names, marks, and brands are registered and/or common law trademarks of Semiconductor Components Industries, LLC dba "**onsemi**" or its affiliates and/or subsidiaries in the United States and/or other countries. **onsemi** owns the rights to a number of patents, trademarks, copyrights, trade secrets, and other intellectual property. A listing of **onsemi**'s product/patent coverage may be accessed at www.onsemi.com/site/pdf/Patent-Marking.pdf. **onsemi** reserves the right to make changes at any time to any products or information herein, without notice. The information herein is provided "as-is" and **onsemi** makes no warranty, representation or guarantee regarding the accuracy of the information, product features, availability, functionality, or suitability of its products for any particular purpose, nor does **onsemi** assume any liability arising out of the application or use of any product or circuit, and specifically disclaims any and all liability, including without limitation special, consequential or incidental damages. Buyer is responsible for its products and applications using **onsemi** products, including compliance with all laws, regulations and safety requirements or standards, regardless of any support or applications information provided by **onsemi**. "Typical" parameters which may be provided in **onsemi** data sheets and/or specifications can and do vary in different applications and actual performance may vary over time. All operating parameters, including "Typicals" must be validated for each customer application by customer's technical experts. **onsemi** does not convey any license under any of its intellectual property rights nor the rights of others. **onsemi** products are not designed, intended, or authorized for use as a critical component in life support systems or any FDA Class 3 medical devices or medical devices with a same or similar classification in a foreign jurisdiction or any devices intended for implantation in the human body. Should Buyer purchase or use **onsemi** products for any such unintended or unauthorized application, Buyer shall indemnify and hold **onsemi** and its officers, employees, subsidiaries, affiliates, and distributors harmless against all claims, costs, damages, and expenses, and reasonable attorney fees arising out of, directly or indirectly, any claim of personal injury or death associated with such unintended or unauthorized use, even if such claim alleges that **onsemi** was negligent regarding the design or manufacture of the part. **onsemi** is an Equal Opportunity/Affirmative Action Employer. This literature is subject to all applicable copyright laws and is not for resale in any manner.

PUBLICATION ORDERING INFORMATION

LITERATURE FULFILLMENT:

Email Requests to: orderlit@onsemi.com

onsemi Website: www.onsemi.com

TECHNICAL SUPPORT

North American Technical Support:

Voice Mail: 1 800-282-9855 Toll Free USA/Canada

Phone: 011 421 33 790 2910

Europe, Middle East and Africa Technical Support:

Phone: 00421 33 790 2910

For additional information, please contact your local Sales Representative